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TPS7A8101-Q1 Low-Noise, Wide-Bandwidth, High PSRR, Low-Dropout 1-A Linear Regulator

Technical [Documents](http://www.ti.com/product/TPS7A8101-Q1?dcmp=dsproject&hqs=td&#doctype2)

-
- AEC-Q100 Qualified With the Following Results: Automotive ADAS ECUs
	- Device Temperature Grade 1: –40°C to 125°C Telematic Control Units Ambient Operating Temperature Range • Audio
	- Device HBM ESD Classification Level H2 High-Speed I/F (PLL and VCO)
	- Device CDM ESD Classification Level C4B
-
-
- -
	-
	-
-
-
-
- temperature variations. 3% Overall Accuracy (Over Load, Line,
-
-
- Package: 3-mm × 3-mm SON-8 **Device Information(1)**

1 Features 2 Applications

Tools & **[Software](http://www.ti.com/product/TPS7A8101-Q1?dcmp=dsproject&hqs=sw&#desKit)**

- Qualified for Automotive Applications RF Power in Automotive Applications
	-
	-
	-
	-

• Low-Dropout 1-A Regulator with Enable **3 Description** Adjustable Output Voltage: 0.8 V to 6 V and the TPS7A8101-Q1 low-dropout linear regulator (LDO) offers very good performance in output noise (Wide-Bandwidth High PSRR: and power-supply rejection ratio (PSRR). This LDO – 80 dB at 1 kHz uses an advanced BiCMOS process and a - 60 dB at 100 kHz **EXECUTE:** PMOSFET pass device to achieve very low noise, excellent transient response, and excellent PSRR

Low Noise: 23.5 µV_{RMS} typical (100 Hz to performance.

The TROTARMS of the intentional the entity of Terms

 100 kHz)
100 kHz 100 kHz)
Stable With 4.7-µF Output Capacitance
reference and feedback loop to achieve a worst-case reference and feedback loop to achieve a worst-case • Excellent Load and Line Transient Response accuracy of 3% over all load, line, process, and

Temperature) This device is fully specified over the temperature Over-Current and Overtemperature Protection range of $T_A = -40^{\circ}C$ to 125°C and is offered in a 3-mm × 3-mm, SON-8 package with a thermal pad. • Very Low Dropout: 170 mV Typical at 1 A

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Typical Power-Supply Ripple Rejection

4 Typical Application Circuit

EXAS

ISTRUMENTS

Table of Contents

5 Revision History

Changes from Original (April 2014) to Revision A **Page Page Page Page Page** • Changed device status from *Product Preview* to *Production Data* ... [1](#page-0-3)

Product Folder Links: *[TPS7A8101-Q1](http://www.ti.com/product/tps7a8101-q1?qgpn=tps7a8101-q1)*

6 Pin Configuration and Functions

Pin Functions

7 Specifications

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted).⁽¹⁾

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated is not implied. Exposure to absolutemaximum-rated conditions for extended periods my affect device reliability.

(2) $V_{(EN)}$ absolute maximum rating is $V_1 + 0.3 V$ or + 7 V, whichever is smaller.

7.2 Handling Ratings

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 Specification.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

7.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* [application report, SPRA953A.](http://www.ti.com/lit/pdf/SPRA953A)

7.5 Electrical Characteristics

Over the temperature range of –40°C ≤ T_A, T_J ≤ 125°C, V_I = V_{Onom} + 0.5 V or 2.2 V (whichever is greater), I_O = 1 mA, V_(EN) = 2.2 V, C_(OUT) = 4.7 μF, C_(NR) = 0.01 μF, and C_(BYPASS) = 0 μF, unless otherwise noted. The device is tested at V_O = 0.8 V and V_O = 6 V. Typical values are at T $_\mathsf{J}$ = 25°C.

(1) Minimum $V_1 = V_O + V_{DO}$ or 2.2 V, whichever is greater.

(2) The TPS7A8101-Q1 does not include external resistor tolerances and it is not tested at this condition: V_O = 0.8 V, 4.5 V ≤ V_I ≤ 6.5 V,

and 750 mA \leq I_{\odot} \leq 1 A because the power dissipation is greater than the maximum rating of the package.

(3) V_{DO} is not measured for fixed output voltage devices with V_O < 1.7 V because minimum V_I = 2.2 V.

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7.6 Typical Characteristics

At V_{Onom} = 3.3 V, V_I = V_{Onom} + 0.5 V or 2.2 V (whichever is greater), I_O = 100 mA, V_(EN) = V_I, C_(IN) = 1 μF, C_(OUT) = 4.7 μF, and C_(NR) = 0.01 μF; all temperature values refer to T_J , unless otherwise noted.

Typical Characteristics (continued)

Texas **INSTRUMENTS**

[TPS7A8101-Q1](http://www.ti.com/product/tps7a8101-q1?qgpn=tps7a8101-q1)

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Typical Characteristics (continued)

Typical Characteristics (continued)

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STRUMENTS

EXAS

Typical Characteristics (continued)

8 Detailed Description

8.1 Overview

The TPS7A8101-Q1 device belongs to a family of new-generation LDO regulators that use innovative circuitry to achieve wide bandwidth and high loop gain, resulting in extremely high PSRR (over a 1-MHz range) even with very low headroom $(V_1 - V_0)$. A noise-reduction capacitor (C_(NR)) at the NR pin and a bypass capacitor (C_(BYPASS)) decrease noise generated by the bandgap reference in order to improve PSRR, while a quick-start circuit fastcharges the noise-reduction capacitor. This family of regulators offers sub-bandgap output voltages, current-limit, and thermal protection, and is fully specified from –40°C to 125°C.

8.2 Functional Block Diagram

Figure 30. Functional Block Diagram

8.3 Feature Description

8.3.1 Internal Current-Limit

The TPS7A8101-Q1 internal current-limit helps protect the regulator during fault conditions. During the currentlimit, the output sources a fixed amount of current that is largely independent of the output voltage. For reliable operation, the device should not be operated in a current-limit state for extended periods of time.

The PMOS pass element in the TPS7A8101-Q1 device has a built-in body diode that conducts current when the voltage at the OUT pin (V_(OUT)) exceeds the voltage at the IN pin (V_(IN)). This current is not limited, so if extended reverse-voltage operation is anticipated, external limiting may be appropriate.

8.3.2 Shutdown

The enable pin (EN) is active high and is compatible with standard-voltage and low-voltage TTL-CMOS levels. When shutdown capability is not required, the EN pin can connect to the IN pin.

Feature Description (continued)

8.3.3 Startup

Through a lower resistance, the bandgap reference can quickly charge the noise-reduction capacitor $(C_{(NR)})$. The TPS7A8101-Q1 device has a *quick-start* circuit to quickly charge C(NR), if present; see [Figure 30.](#page-10-5) At startup, this quick-start switch is closed, with only 33 kΩ of resistance between the bandgap reference and the NR pin. The quick-start switch opens approximately 100 ms after any device-enabling event, and the resistance between the bandgap reference and the NR pin becomes higher in value (approximately 250 kΩ) to form a very-good lowpass (RC) filter. This low-pass filter reduces the noise present on the reference voltage; therefore, reducing the noise on the output.

Inrush current can cause problems in many applications. The 33-kΩ resistance during the startup period is intentionally placed between the bandgap reference and the NR pin in order to slow down the reference voltage rampup, thus reducing the inrush current.

Use [Equation 1](#page-11-2) to calculate the startup time with other $C_{(NR)}$ values. For example, the capacitance of connecting the recommended C_(NR) value of 0.47 µF along with the 33-kQ resistance causes an 80-ms RC delay (approximately).

$$
t_{st}(s) = 170000 \times C_{(NR)}(F)
$$
 (1)

Although the noise-reduction effect is nearly saturated at 0.47 μ F, connecting a C_(NR) value greater than 0.47 μ F can additionally help reduce noise. However, when connecting a $C_{(NR)}$ value greater than 0.47 μ F, the startup time is extremely long because the quick-start switch opens after approximately 100 ms. That is, if $C_{(NR)}$ is not fully charged during this 100-ms period, C_(NR) finishes charging through a higher resistance of 250 kΩ, and takes much longer to fully charge.

NOTE

A low-leakage capacitor should be used for $C_{(NR)}$. Most ceramic capacitors are suitable

8.3.4 Undervoltage Lockout (UVLO)

The TPS7A8101-Q1 device uses an undervoltage-lockout (UVLO) circuit to ensure that the output is shut off until the internal circuitry has enough voltage to operate properly. The UVLO circuit has a deglitch feature so that the circuit typically ignores undershoot transients on the input if the duration is less than 50-μs.

8.4 Device Functional Modes

Driving the EN pin over 1.2 V for V₁ between 2.2 V to 3.6 V or 1.35 V for V₁ between 3.6 V and 6.5 V turns on the regulator. Driving the EN pin below 0.4 V causes the regulator to enter shutdown mode.

In shutdown, the current consumption of the device is reduced to 0.02 µA typically.

9 Application and Implementation

9.1 Application Information

The TPS7A8101-Q1 device belongs to a family of new-generation LDO regulators that use innovative circuitry to achieve wide bandwidth and high loop gain, resulting in extremely high PSRR (over a 1-MHz range) even with very low headroom (V_I – V_O). A noise-reduction capacitor (C_(NR)) at the NR pin and a bypass capacitor (C_(BYPASS)) decrease noise generated by the bandgap reference in order to improve PSRR, while a quick-start circuit fastcharges the noise-reduction capacitor. This family of regulators offers sub-bandgap output voltages, current-limit, and thermal protection, and is fully specified from –40°C to 125°C.

9.2 Typical Application

[Figure 31](#page-12-3) shows the connections for the device.

Figure 31. Typical Application Circuit

The voltage on the FB pin sets the output voltage and is determined by the values of the resistors R1 and R2. Use [Equation 2](#page-12-4) to calculate the values of R1 and R2 any voltage.

$$
V_{\rm O} = \frac{\left(\text{R1} + \text{R2}\right)}{\text{R2}} \times 0.8\tag{2}
$$

[Table 1](#page-13-0) lists sample resistor values for common output voltages. In [Table 1](#page-13-0), E96 series resistors are used, and all values meet 1% of the target V_O , assuming resistors with zero error. For the actual design, pay attention to any resistor error-factors. Using lower values for R1 and R2 reduces the noise injected into the FB pin.

9.2.1 Design Requirements

9.2.1.1 Dropout Voltage

The TPS7A8101-Q1 device uses a PMOS pass transistor to achieve low dropout. When $(V_1 - V_{Onom})$ is less than the dropout voltage (V_{DO}) , the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $r_{DS(on)}$ of the PMOS pass element. V_{DO} is proportional to the output current because the PMOS device in dropout functions in the same way as a resistor.

As with any linear regulator, PSRR and transient responses are degraded as $(V_1 - V_0)$ approaches dropout. [Figure 19](#page-7-0) and [Figure 20](#page-7-0) in the *[Typical Characteristics](#page-5-0)* section shown this effect.

9.2.1.2 Minimum Load

The TPS7A8101-Q1 device is stable and functions well with no output load. Traditional PMOS-LDO regulators suffer from lower loop gain at very light output loads. The TPS7A8101-Q1 device employs an innovative lowcurrent mode circuit to increase loop gain under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current.

9.2.1.3 Input And Output Capacitor Requirements

Although an input capacitor is not required for stability, connecting a 0.1-µF to 1-µF low-equivalent seriesresistance (ESR) capacitor from the input supply near the regulator to ground is good analog-design practice. This capacitor counteracts reactive input sources and improves transient response and ripple rejection. A highervalue capacitor may be necessary if large, fast load transients are anticipated or if the device is located several inches from the power source. If source impedance is not sufficiently low, a 0.1-μF input capacitor may be necessary to ensure stability.

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Typical Application (continued)

The TPS7A8101-Q1 device is designed to be stable with standard ceramic capacitors of capacitance values 4.7 μF or larger. This device was evaluated using a 10-μF ceramic capacitor of 10-V rating, 10% tolerance, X5R type, and 0805 size $(2 \text{ mm} \times 1,25 \text{ mm})$.

X5R-type and X7R-type capacitors are highly recommended because they have minimal variation in capacitance and ESR over temperature. The maximum ESR should be less than 1 $Ω$.

Table 1. Recommended Feedback Resistor Values for Common Output Voltages

 $C_{\text{(OUTPUT)}}$ 10 µF $C_{(IN)}$ 10 µF

Table 2. Recommended Capacitor Values

9.2.1.4 Transient Response

As with any regulator, increasing the size of the output capacitor reduces overshoot and undershoot magnitude but increases the duration of the transient response. Using a larger noise-reduction capacitor ($C_{(NR)}$), bypass capacitor $(C_{(BYPASS)})$, or both types of capacitors can improve line-transient performance.

9.2.2 Detailed Design Procedure

9.2.2.1 Output Noise

In most LDOs, the bandgap is the dominant noise source. If a noise reduction capacitor $(C_{(NR)})$ is used with the TPS7A8101-Q1 device, the bandgap does not contribute significantly to noise. Instead, noise is dominated by the output resistor-divider and the error-amplifier input. If a bypass capacitor ($C_{(BYPASS)}$) across the high-side feedback resistor (R1) is used with the TPS7A8101-Q1 device, noise from these other sources can also be significantly reduced.

To maximize noise performance in a given application, use a 0.47-μF noise-reduction capacitor plus a 0.47-μF bypass capacitor.

9.2.3 Application Curves

[TPS7A8101-Q1](http://www.ti.com/product/tps7a8101-q1?qgpn=tps7a8101-q1)

10 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2.2 V and 6.5 V. The input voltage range should provide adequate headroom in order for the device to have a regulated output. This input supply should be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

11 Layout

11.1 Layout Guidelines

11.1.1 Board Layout Recommendations To Improve PSRR And Noise Performance

To improve AC performance such as PSRR, output noise, and transient response, designing with separate ground planes for V_1 and V_0 , with each ground plane connected only at the GND pin of the device, is recommended. In addition, the ground connection for the noise-reduction capacitor should connect directly to the GND pin of the device.

High ESR capacitors may degrade PSRR.

11.2 Layout Example

Figure 44. TPS7A8101-Q1 Layout Example

11.3 Thermal Information

11.3.1 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage because of overheating.

Any activation of the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to 125°C (maximum). To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least 35°C above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worstcase load.

The internal protection circuitry of the TPS7A8101-Q1 device has been designed to protect against overload conditions. The internal thermal protection circuitry was not intended to replace proper heatsinking. Continuously running the TPS7A8101-Q1 device into thermal shutdown degrades device reliability.

11.3.2 Package Mounting

See the [Mechanical, Packaging, and Orderable Information](#page-20-5) section for solder pad footprint recommendations and recommended land patterns.

11.3.3 Power Dissipation

Knowing the device power dissipation and proper sizing of the thermal plane that is connected to the tab or pad is critical to avoiding thermal shutdown and ensuring reliable operation.

The power dissipation of the device depends on input voltage and load conditions. To calculate the device power dissipation, use [Equation 3](#page-17-1).

$$
P_D = (V_1 - V_0) \times I_0 \tag{3}
$$

Using the lowest possible input voltage necessary to achieve the required output voltage regulation minimizes power dissipation and achieves greater efficiency.

On the SON (DRB) package, the primary conduction path for heat is through the exposed pad to the printed circuit board (PCB). The pad can be connected to ground or can be left floating; however, the pad should be attached to an appropriate amount of copper PCB area to ensure the device does not overheat. The maximum junction-to-ambient thermal resistance depends on the maximum ambient temperature, maximum device junction temperature, and power dissipation of the device. Calculate the maximum junction-to-ambient thermal resistance using [Equation 4.](#page-17-2)

$$
R_{\theta JA}=\frac{\left(125^{\circ}C-T_{A}\right)}{P_{D}}
$$

(4)

Once the maximum R_{0JA} value is calculated, use [Figure 45](#page-18-0) to estimate the minimum amount of PCB copper area needed for appropriate heatsinking.

Thermal Information (continued)

Note: The R_{θJA} value at board size of 9 in² (that is, 3 in \times 3 in) is a JEDEC standard.

Figure 45. RθJA vs Board Size

[Figure 45](#page-18-0) shows the variation of $R_{\theta JA}$ as a function of ground plane copper area in the board. Figure 45 is intended as a guideline only to demonstrate the effects of heat spreading in the ground plane and should not be used to estimate actual thermal performance in real application environments.

NOTE

When the device is mounted on an application PCB, using Ψ_{JT} and Ψ_{JB} , as explained in the section is strongly recommended.

11.3.4 Estimating Junction Temperature

Using the thermal metrics ΨJT and ΨJB, as shown in the *[Thermal Information](#page-3-4)* table, the junction temperature can be estimated with the corresponding equations, [Equation 5](#page-18-1) and [Equation 6](#page-18-2). For backwards compatibility, an older *θJC,Top* parameter is listed as well.

$$
\phi_{JT}: T_J = T_T + \phi_{JT} \times P_D
$$

where

- P_D is the power dissipation (see [Equation 4](#page-17-2))
- T_T is the temperature at the center-top of the IC package (5)

 φ_{JB} : T_J = T_B + φ_{JB} × P_D

where

T_B is the PCB temperature measured 1-mm away from the IC package *on the PCB surface* as shown in Figure 46 $F_{\text{Figure 46}} \hspace{1.5cm} (6)$ $F_{\text{Figure 46}} \hspace{1.5cm} (6)$ $F_{\text{Figure 46}} \hspace{1.5cm} (6)$

Thermal Information (continued)

NOTE Both T_T and T_B can be measured on actual application boards using an infrared thermometer.

For more information about measuring T_T and T_B , see TI's application report [SBVA025,](http://www.ti.com/lit/pdf/SBVA025) Using New Thermal *Metrics*.

As shown in [Figure 47](#page-19-1), the new thermal metrics (Ψ_{JT} and Ψ_{JB}) have very little dependency on board size. That is, using Ψ_{JT} or Ψ_{JB} with [Equation 5](#page-18-1) is a good way to estimate T_J by simply measuring T_T or T_B, regardless of the application board size.

Figure 47. ΨJT and ΨJB vs Board Size

For a more detailed discussion of why TI does not recommend using $R_{\theta JC(top)}$ to determine thermal characteristics, refer to TI's application report [SBVA025,](http://www.ti.com/lit/pdf/SBVA025) *Using New Thermal Metrics*. For further information, refer to TI's application report [SPRA953](http://www.ti.com/lit/pdf/SPRA953), *IC Package Thermal Metrics*.

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- *LDO noise examined in detail*, [SLYT489](http://www.ti.com/lit/pdf/SLYT489)
- *LDO Performance Near Dropout*, [SBVA029](http://www.ti.com/lit/pdf/SBVA029)
- *TPS7A8101EVM Evaluation Module*, [SLVU600](http://www.ti.com/lit/pdf/SLVU600)
- *Wide Bandwidth PSRR of LDOs* by Nogawa and Van Renterghem in *Bodo's Power Systems® : Electronics in Motion and Conversion*, March 2011

12.2 Trademarks

Bodo's Power Systems is a registered trademark of Arlt Bodo. All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.4 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TPS7A8101-Q1 :

PACKAGE OPTION ADDENDUM

• Catalog: [TPS7A8101](http://focus.ti.com/docs/prod/folders/print/tps7a8101.html)

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

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PACKAGE MATERIALS INFORMATION

www.ti.com 8-May-2023

*All dimensions are nominal

DRB8

GENERIC PACKAGE VIEW

VSON - 1 mm max height
PLASTIC SMALL OUTLINE - NO LEAD

Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L

PACKAGE OUTLINE

DRB0008A VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

DRB0008A VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRB0008A VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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